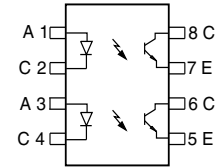
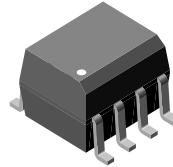




Optocoupler, Phototransistor Output, Dual Channel, SOIC-8 package

Features

- Two Channel Coupler
- SOIC-8A Surface Mountable Package
- Standard Lead Spacing of .05 "
- Available only on Tape and Reel Option (Conforms to EIA Standard 481-2)
- Isolation Test Voltage, 3000 V_{RMS}
- Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering



1179018

Agency Approvals

- UL - File No. E52744 System Code Y

Description

The ILD205T/ 206T/ 207T/ 211T/ 213T/ 217T are optically coupled pairs with a Gallium Arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD205T/ 206T/ 207T/ 211T/ 213T/ 217T come in a standard SOIC-8A small outline package for surface mounting which makes it ideally suited for high density applications with limited space. In addition to eliminating through-holes requirements, this package conforms to standards for surface mounted devices.

A specified minimum and maximum CTR allows a narrow tolerance in the electrical design of the adjacent circuits. The high BV_{CEO} of 70 V gives a higher safety margin compared to the industry standard of 30 V.

Order Information

| Part | Remarks |
|---------|-------------------------|
| ILD205T | CTR 40 - 80 %, SOIC-8 |
| ILD206T | CTR 63 - 125 %, SOIC-8 |
| ILD207T | CTR 100 - 200 %, SOIC-8 |
| ILD211T | CTR > 20 %, SOIC-8 |
| ILD213T | CTR > 100 %, SOIC-8 |
| ILD217T | CTR > 100 %, SOIC-8 |

For additional information on the available options refer to Option Information.

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

Input

| Parameter | Test condition | Symbol | Value | Unit |
|--|-----------------|-------------------|-------|-------|
| Peak reverse voltage | | V _R | 6.0 | V |
| Peak pulsed current | 1.0 μs, 300 pps | | 1.0 | A |
| Continuous forward current per channel | | | 30 | mA |
| Power dissipation | | P _{diss} | 50 | mW |
| Derate linearly from 25 °C | | | 0.66 | mW/°C |

Output

| Parameter | Test condition | Symbol | Value | Unit |
|-------------------------------------|----------------|------------|-------|-------|
| Collector-emitter breakdown voltage | | BV_{CEO} | 70 | V |
| Emitter-collector breakdown voltage | | BV_{ECO} | 7.0 | V |
| Power dissipation per channel | | P_{diss} | 125 | mW |
| Derate linearly from 25 °C | | | 1.67 | mW/°C |

Coupler

| Parameter | Test condition | Symbol | Value | Unit |
|--|----------------|-----------|---------------|-------|
| Total package dissipation ambient (2 LEDs + 2 detectors, 2 channels) | | P_{tot} | 300 | mW |
| Derate linearly from 25 °C | | | 4.0 | mW/°C |
| Storage temperature | | T_{stg} | - 55 to + 150 | °C |
| Operating temperature | | T_{amb} | - 55 to + 100 | °C |
| Soldering time from 260 °C | | T_{sld} | 10 | sec. |

Electrical Characteristics

$T_{amb} = 25\text{ °C}$, unless otherwise specified

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

Input

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
|-----------------|----------------------|--------|-----|------|------|---------------|
| Forward voltage | $I_F = 10\text{ mA}$ | V_F | | 1.2 | 1.55 | V |
| Reverse current | $V_R = 6.0\text{ V}$ | I_R | | 0.1 | 100 | μA |
| Capacitance | $V_R = 0$ | C_O | | 25 | | pF |

Output

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
|-------------------------------------|------------------------------------|------------|-----|------|-----|------|
| Collector-emitter breakdown voltage | $I_C = 10\text{ }\mu\text{A}$ | BV_{CEO} | 70 | | | V |
| Emitter-collector breakdown voltage | $I_E = 10\text{ }\mu\text{A}$ | BV_{ECO} | 7.0 | | | V |
| Collector-emitter leakage current | $V_{CE} = 10\text{ V}$, $I_F = 0$ | I_{CEO} | | 5.0 | 50 | nA |
| Collector-emitter capacitance | $V_{CE} = 0$ | C_{CE} | | 10 | | pF |

Coupler

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
|--------------------------------------|--|---------------|------|------|-----|-----------|
| Collector-emitter saturation voltage | $I_F = 10\text{ mA}$, $I_C = 2.5\text{ mA}$ | $V_{CE(sat)}$ | | | 0.4 | V |
| Capacitance (input-output) | | C_{IO} | | 0.5 | | pF |
| Isolation test voltage | $t = 1.0\text{ sec.}$ | V_{ISO} | 3000 | | | V_{RMS} |
| Resistance, input to output | | R_{IO} | | 100 | | $G\Omega$ |



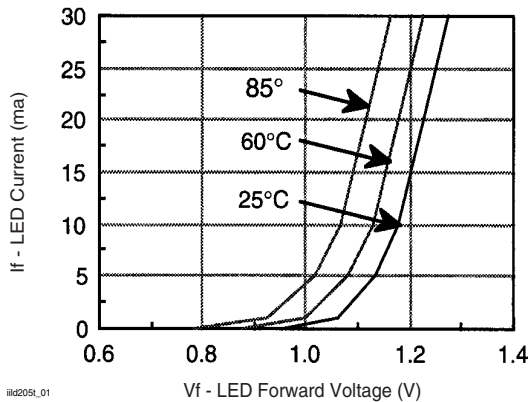
Current Transfer Ratio

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|---------------------------|--|---------|------------|-----|------|-----|------|
| DC Current Transfer Ratio | $V_{CE} = 5.0 \text{ V}, I_F = 10 \text{ mA}$ | ILD205T | CTR_{DC} | 40 | | 80 | % |
| | | ILD206T | CTR_{DC} | 63 | | 125 | % |
| | | ILD207T | CTR_{DC} | 100 | | 200 | % |
| | | ILD211T | CTR_{DC} | 20 | | | % |
| | | ILD213T | CTR_{DC} | 100 | | | % |
| | $V_{CE} = 5.0 \text{ V}, I_F = 1.0 \text{ mA}$ | ILD205T | CTR_{DC} | 13 | 30 | | % |
| | | ILD206T | CTR_{DC} | 22 | 45 | | % |
| | | ILD217T | CTR_{DC} | 100 | 120 | | % |

Switching Characteristics

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
|---------------|--|-----------|-----|------|-----|---------------|
| Turn-on time | $I_C = 2.0 \text{ mA}, R_L = 100 \Omega, V_{CC} = 5.0 \text{ V}$ | t_{on} | 5.0 | | | μs |
| Turn-off time | $I_C = 2.0 \text{ mA}, R_L = 100 \Omega, V_{CC} = 5.0 \text{ V}$ | t_{off} | 4.0 | | | μs |

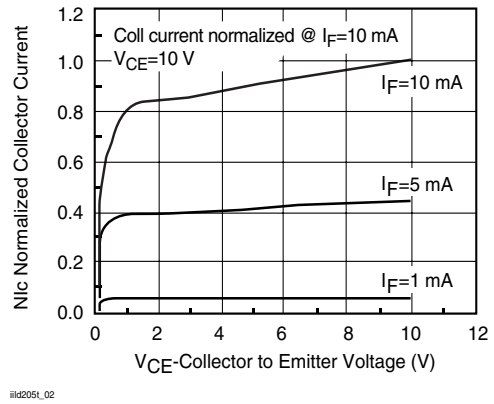
Typical Characteristics ($T_{amb} = 25 \text{ }^\circ\text{C}$ unless otherwise specified)



ild205L_01

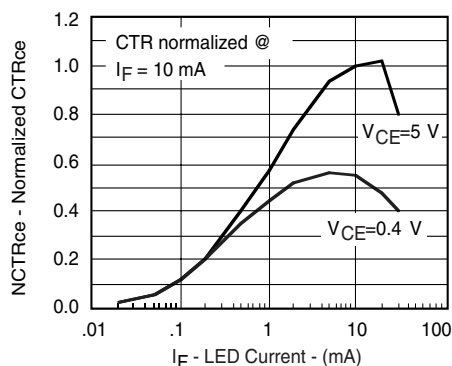
V_f - LED Forward Voltage (V)

Fig. 1 Forward Current vs. Forward Voltage



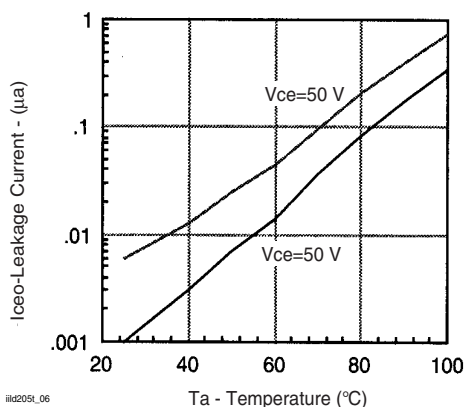
ild205L_02

Fig. 2 Collector-Emitter Current vs. Temperature



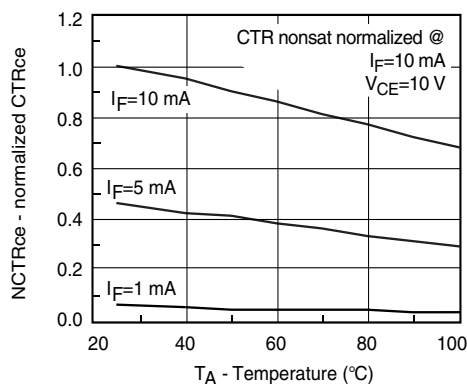
ild205t_03

Fig. 3 Normalized CTR_{ce} vs. Forward Current



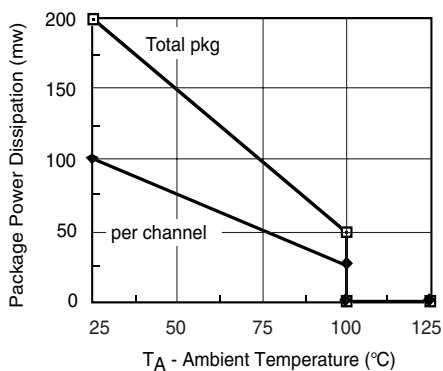
ild205t_06

Fig. 6 Collector Current vs. Ambient Temperature



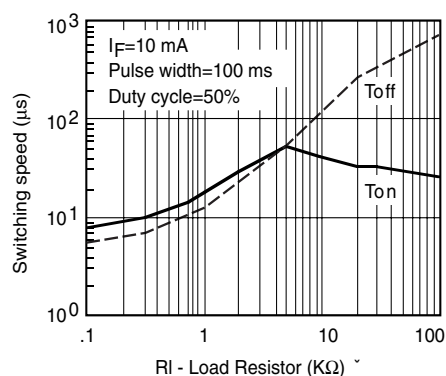
ild205t_04

Fig. 4 Current Transfer Ratio (normalized) vs. Ambient Temperature



ild205t_07

Fig. 7 Power Dissipation vs. Ambient Temperature



ild205t_01

Fig. 5 Switching Speed vs. Load Resistor

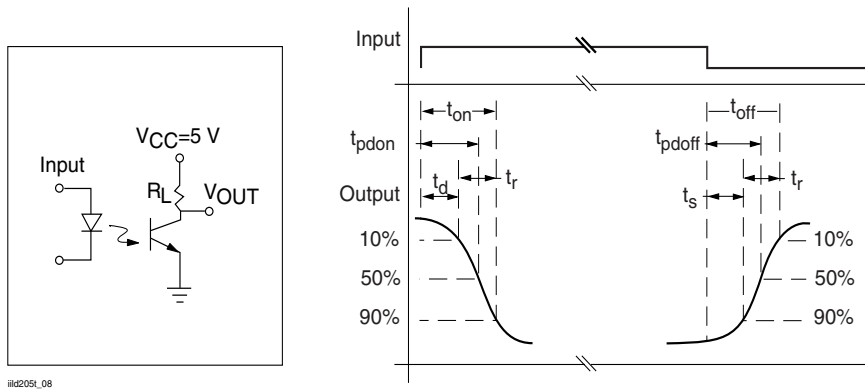
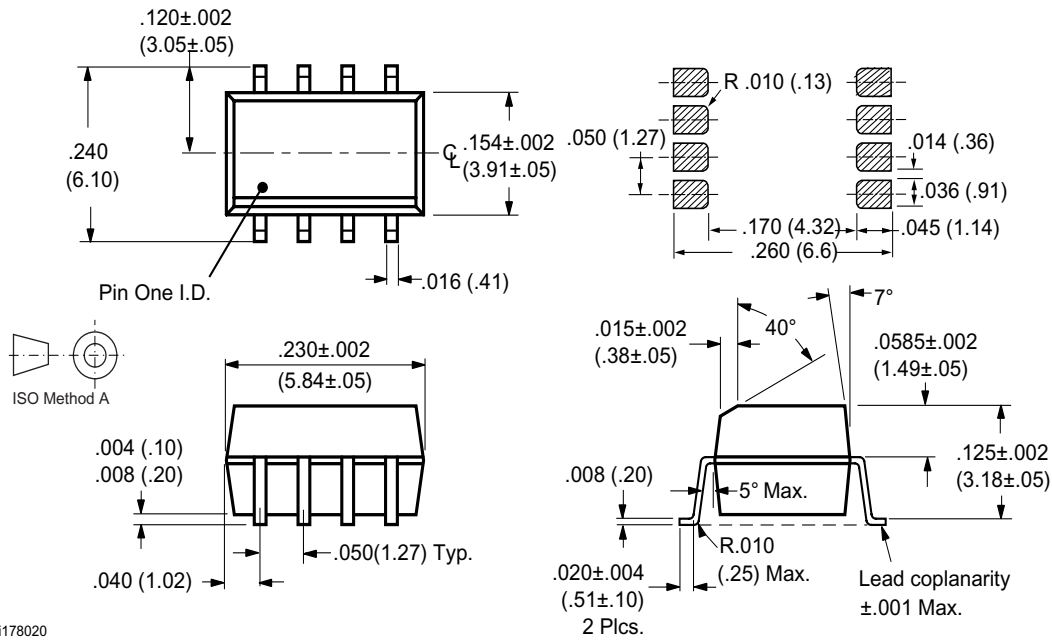


Fig. 8 Switching Time Test Schematic and Waveform

Package Dimensions in Inches (mm)



i178020



Vishay Semiconductors

Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design
and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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